# 2SK3576-T1B-A-VB Datasheet

## N-Channel 20 V (D-S) MOSFET

| PRODUCT SUMMARY | | | |
|---|---|---|---|
| $V_{DS}$ (V) | $R_{DS(on)}$ (Ω) | $I_D$ (A)[e] | $Q_g$ (Typ.) |
| 20 | 0.022 at $V_{GS}$ = 4.5 V | 6[a] | 8.8 nC |
| | 0.028 at $V_{GS}$ = 2.5 V | 6[a] | |
| | 0.039 at $V_{GS}$ = 1.8 V | 5.6 | |

### FEATURES

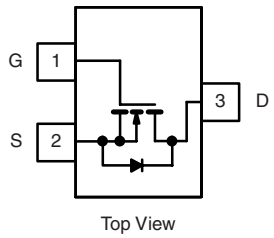
- **Halogen-free According to IEC 61249-2-21 Definition**
- Trench Power MOSFET
- 100 % $R_g$ Tested
- Compliant to RoHS Directive 2002/95/EC

Pb-free
RoHS COMPLIANT
HALOGEN FREE

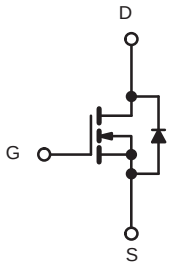
### APPLICATIONS

- DC/DC Converters
- Load Switch for Portable Applications

SOT-23




Top View




N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS $T_A$ = 25 °C, unless otherwise noted | | | | |
|---|---|---|---|---|
| **Parameter** | | **Symbol** | **Limit** | **Unit** |
| Drain-Source Voltage | | $V_{DS}$ | 20 | V |
| Gate-Source Voltage | | $V_{GS}$ | ± 12 | |
| Continuous Drain Current ($T_J$ = 150 °C) | $T_C$ = 25 °C | $I_D$ | 6[a] | A |
| | $T_C$ = 70 °C | | 5.1 | |
| | $T_A$ = 25 °C | | 5[b, c] | |
| | $T_A$ = 70 °C | | 4[b, c] | |
| Pulsed Drain Current | | $I_{DM}$ | 20 | |
| Continuous Source-Drain Diode Current | $T_C$ = 25 °C | $I_S$ | 1.75 | |
| | $T_A$ = 25 °C | | 1.04[b, c] | |
| Maximum Power Dissipation | $T_C$ = 25 °C | $P_D$ | 2.1 | W |
| | $T_C$ = 70 °C | | 1.3 | |
| | $T_A$ = 25 °C | | 1.25[b, c] | |
| | $T_A$ = 70 °C | | 0.8[b, c] | |
| Operating Junction and Storage Temperature Range | | $T_J$, $T_{stg}$ | - 55 to 150 | °C |
| Soldering Recommendations (Peak Temperature) | | | 260 | |

| THERMAL RESISTANCE RATINGS | | | | | |
|---|---|---|---|---|---|
| **Parameter** | | **Symbol** | **Typical** | **Maximum** | **Unit** |
| Maximum Junction-to-Ambient[b, d] | t ≤ 5 s | $R_{thJA}$ | 80 | 100 | °C/W |
| Maximum Junction-to-Foot (Drain) | Steady State | $R_{thJF}$ | 40 | 60 | |

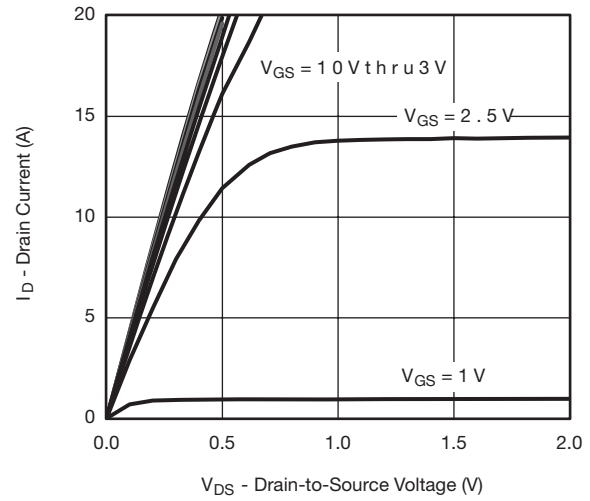
Notes:
a. Package limited
b. Surface Mounted on 1" x 1" FR4 board.
c. t = 5 s.
d. Maximum under steady state conditions is 125 °C/W.
e. Based on $T_C$ = 25 °C.

| **SPECIFICATIONS** $T_J$ = 25 °C, unless otherwise noted | | | | | | |
|---|---|---|---|---|---|---|
| **Parameter** | **Symbol** | **Test Conditions** | **Min.** | **Typ.** | **Max.** | **Unit** |
| **Static** | | | | | | |
| Drain-Source Breakdown Voltage | $V_{DS}$ | $V_{GS}$ = 0 V, $I_D$ = 250 µA | 20 | | | V |
| $V_{DS}$ Temperature Coefficient | $\Delta V_{DS}/T_J$ | $I_D$ = 250 µA | | 25 | | mV/°C |
| $V_{GS(th)}$ Temperature Coefficient | $\Delta V_{GS(th)}/T_J$ | | | - 2.6 | | |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | $V_{DS}$ = $V_{GS}$ , $I_D$ = 250 µA | 0.45 | | 1.0 | V |
| Gate-Source Leakage | $I_{GSS}$ | $V_{DS}$ = 0 V, $V_{GS}$ = ± 8 V | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | $V_{DS}$ = 20 V, $V_{GS}$ = 0 V | | | 1 | µA |
| | | $V_{DS}$ = 20 V, $V_{GS}$ = 0 V, $T_J$ = 70 °C | | | 10 | |
| On-State Drain Current[a] | $I_{D(on)}$ | $V_{DS} \leq$ 5 V, $V_{GS}$ = 4.5 V | 20 | | | A |
| Drain-Source On-State Resistance[a] | $R_{DS(on)}$ | $V_{GS}$ = 4.5 V, $I_D$ = 5.0 A | | 0.022 | | Ω |
| | | $V_{GS}$ = 2.5 V, $I_D$ = 4.7 A | | 0.028 | | |
| | | $V_{GS}$ = 1.8 V, $I_D$ = 4.3 A | | 0.039 | | |
| Forward Transconductance[a] | $g_{fs}$ | $V_{DS}$ = 10 V, $I_D$ = 5.0 A | | 24 | | S |
| **Dynamic[b]** | | | | | | |
| Input Capacitance | $C_{iss}$ | $V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 1 MHz | | 865 | | pF |
| Output Capacitance | $C_{oss}$ | | | 105 | | |
| Reverse Transfer Capacitance | $C_{rss}$ | | | 55 | | |
| Total Gate Charge | $Q_g$ | $V_{DS}$ = 10 V, $V_{GS}$ = 5 V, $I_D$ = 5.0 A | | 12 | 18 | nC |
| | | $V_{DS}$ = 10 V, $V_{GS}$ = 4.5 V, $I_D$ = 5.0 A | | 8.8 | 14 | |
| Gate-Source Charge | $Q_{gs}$ | | | 1.1 | | |
| Gate-Drain Charge | $Q_{gd}$ | | | 0.7 | | |
| Gate Resistance | $R_g$ | f = 1 MHz | 0.5 | 2.4 | 4.8 | Ω |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}$ = 10 V, $R_L$ = 2.2 Ω<br>$I_D \cong$ 4 A, $V_{GEN}$ = 4.5 V, $R_g$ = 1 Ω | | 8 | 16 | ns |
| Rise Time | $t_r$ | | | 17 | 26 | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 31 | 47 | |
| Fall Time | $t_f$ | | | 8 | 16 | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}$ = 10 V, $R_L$ = 2.2 Ω<br>$I_D \cong$ 4 A, $V_{GEN}$ = 5 V, $R_g$ = 1 Ω | | 5 | 10 | |
| Rise Time | $t_r$ | | | 13 | 20 | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 21 | 32 | |
| Fall Time | $t_f$ | | | 6 | 12 | |
| **Drain-Source Body Diode Characteristics** | | | | | | |
| Continuous Source-Drain Diode Current | $I_S$ | $T_C$ = 25 °C | | | 1.75 | A |
| Pulse Diode Forward Current | $I_{SM}$ | | | | 20 | |
| Body Diode Voltage | $V_{SD}$ | $I_S$ = 4 A, $V_{GS}$ = 0 V | | 0.75 | 1.2 | V |
| Body Diode Reverse Recovery Time | $t_{rr}$ | $I_F$ = 4 A, dI/dt = 100 A/µs, $T_J$ = 25 °C | | 12 | 20 | ns |
| Body Diode Reverse Recovery Charge | $Q_{rr}$ | | | 5 | 10 | nC |
| Reverse Recovery Fall Time | $t_a$ | | | 7 | | ns |
| Reverse Recovery Rise Time | $t_b$ | | | 5 | | |

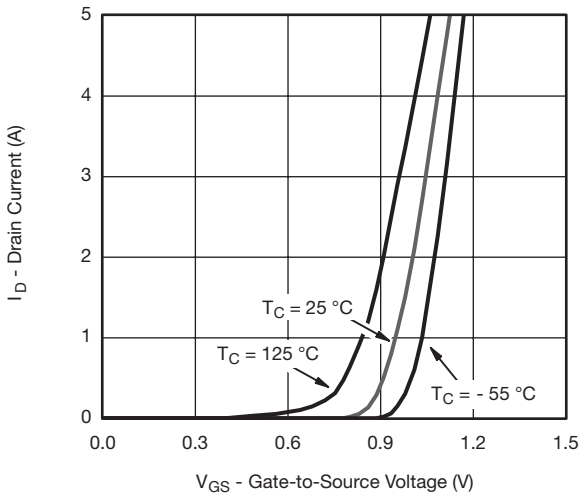
Notes:
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %
b. Guaranteed by design, not subject to production testing.

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

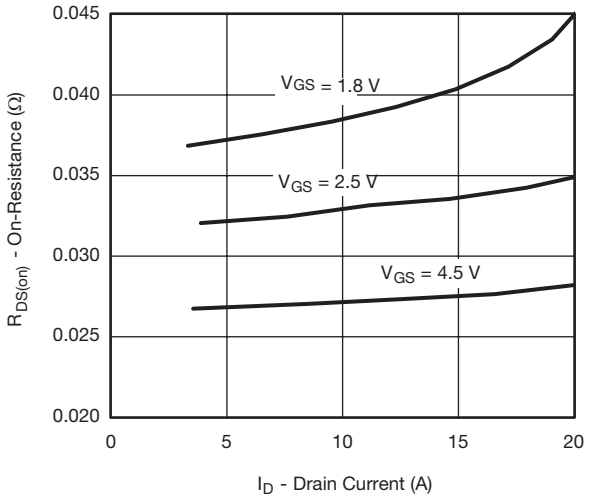
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



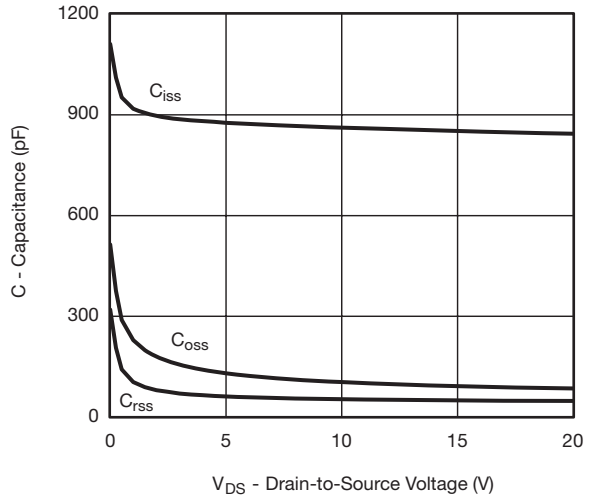

**Output Characteristics**



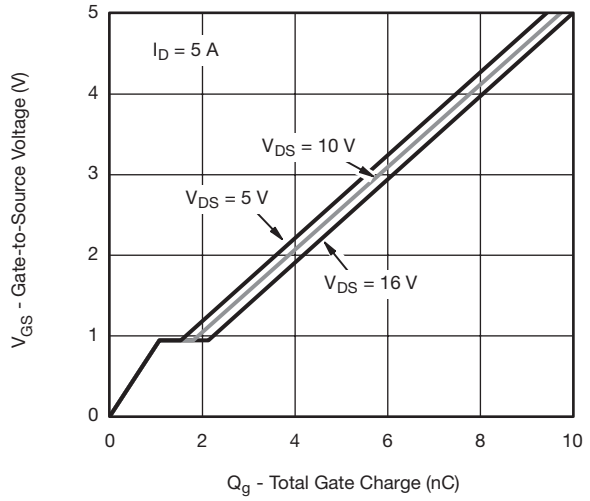

**Transfer Characteristics**



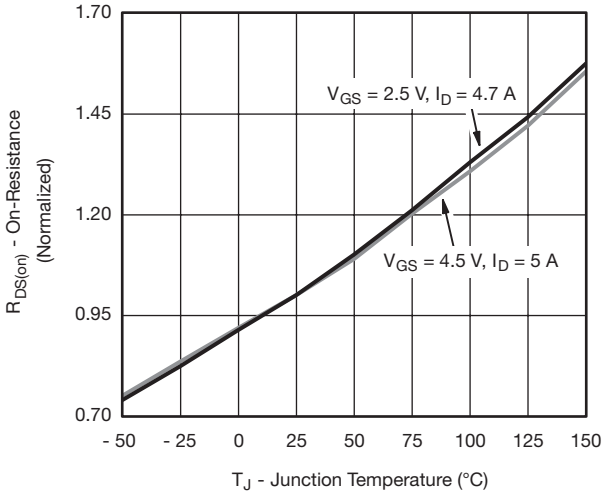

**On-Resistance vs. Drain Current and Gate Voltage**




**Capacitance**

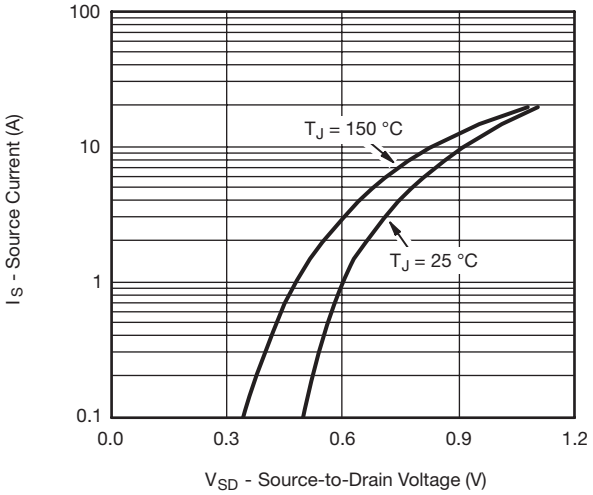



**Gate Charge**

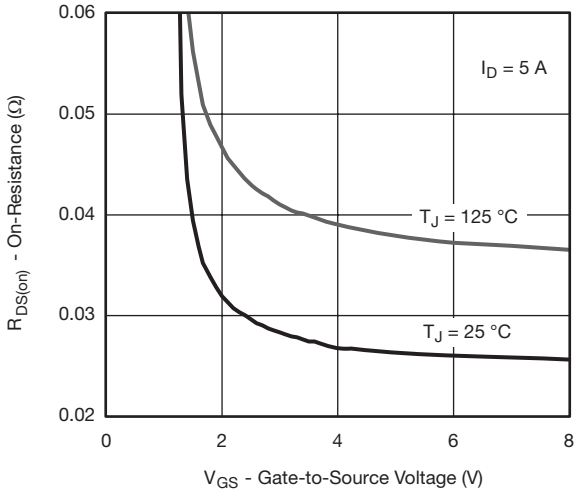



**On-Resistance vs. Junction Temperature**

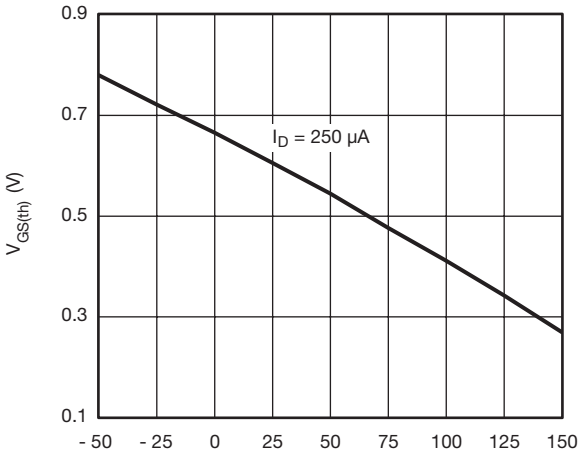
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



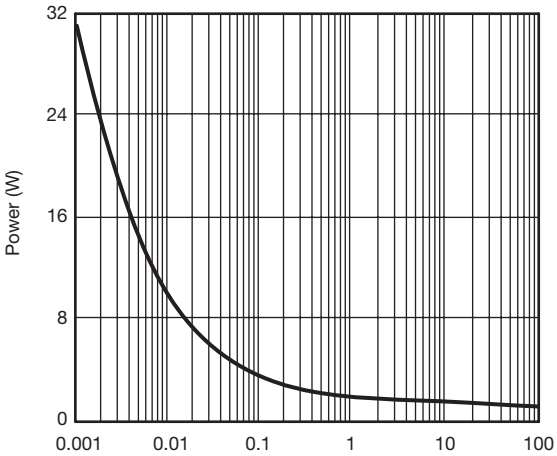

**Source-Drain Diode Forward Voltage**



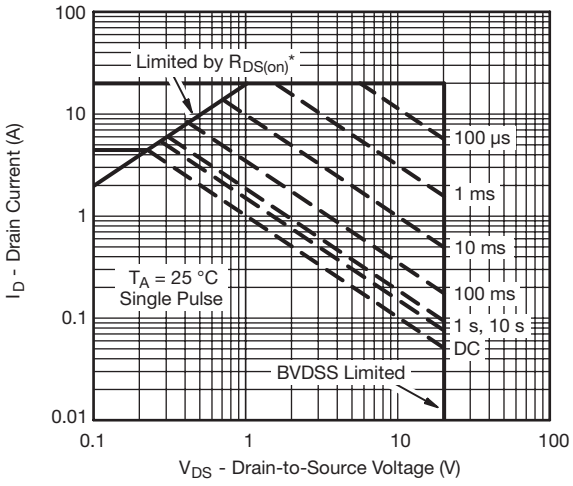

**On-Resistance vs. Gate-to-Source Voltage**




**Threshold Voltage**



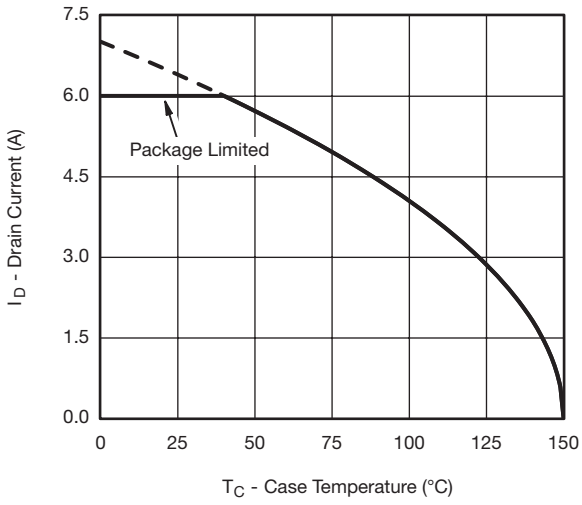

**Single Pulse Power (Junction-to-Ambient)**



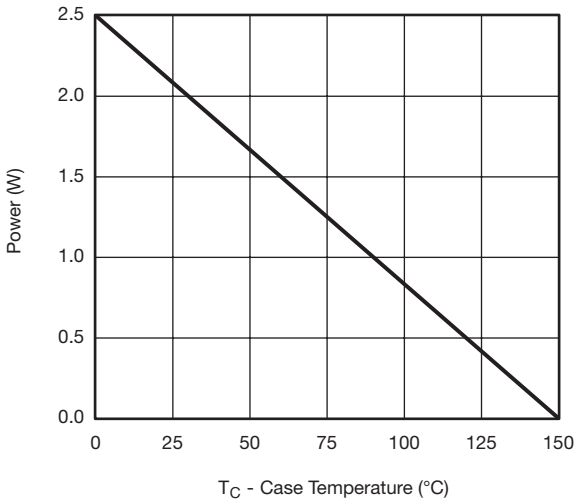

* $V_{GS}$ > minimum $V_{GS}$ at which $R_{DS(on)}$ is specified

**Safe Operating Area, Junction-to-Ambient**

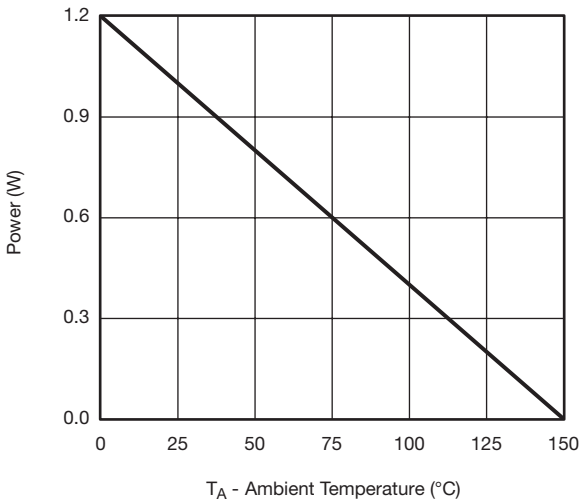
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted




**Current Derating***



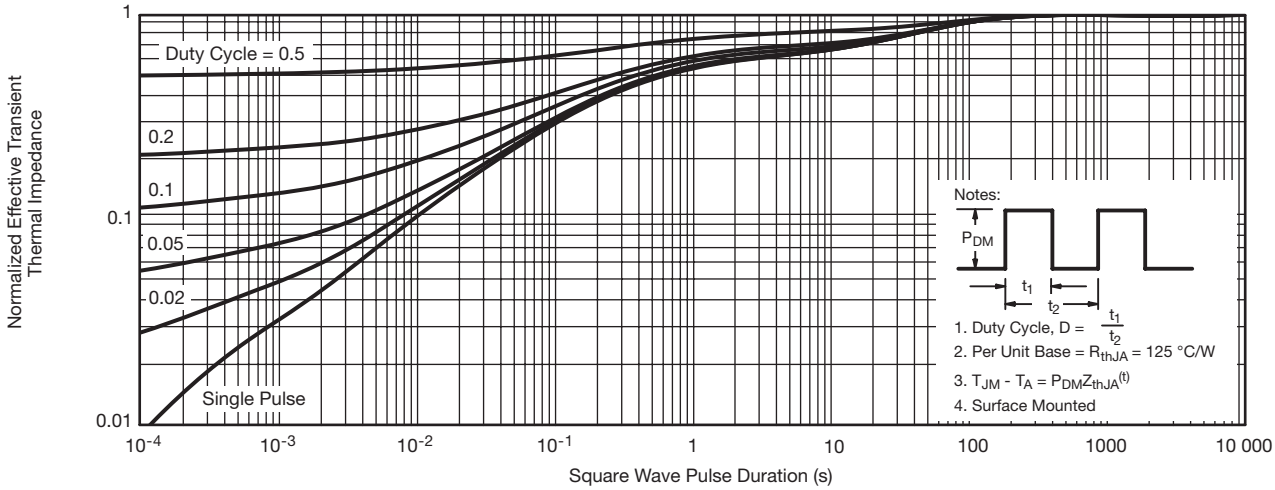

**Power Derating, Junction-to-Foot**



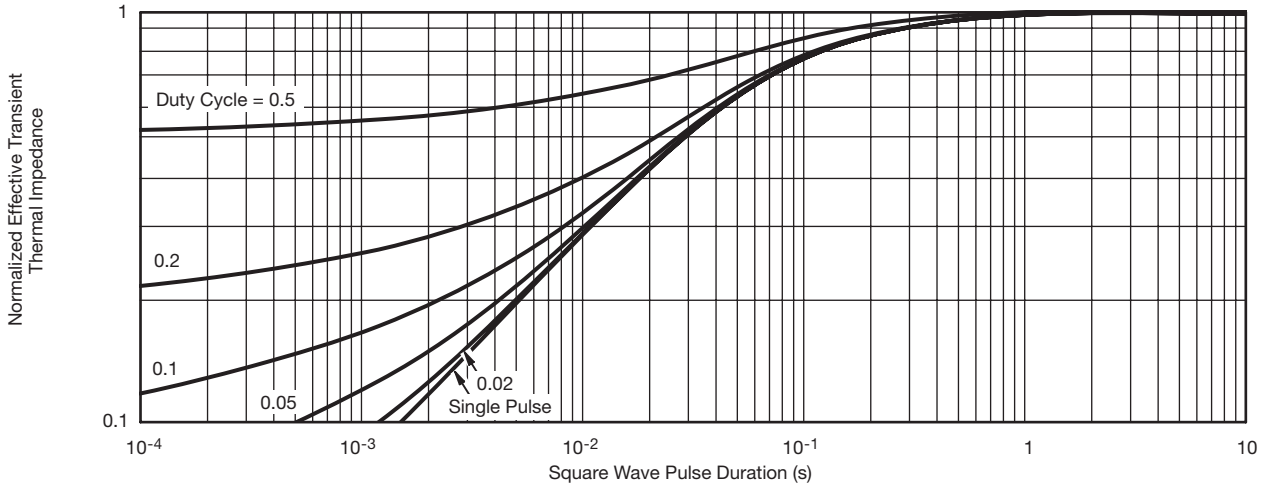

**Power Derating, Junction-to-Ambient**

* The power dissipation $P_D$ is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

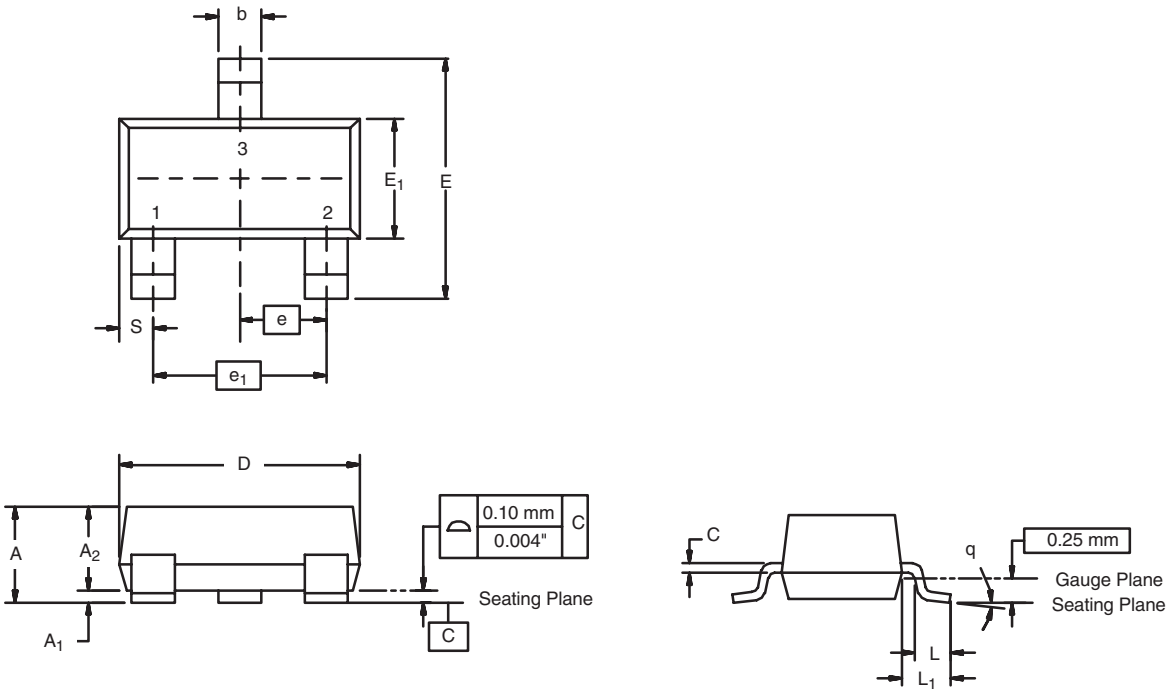



**Normalized Thermal Transient Impedance, Junction-to-Ambient**



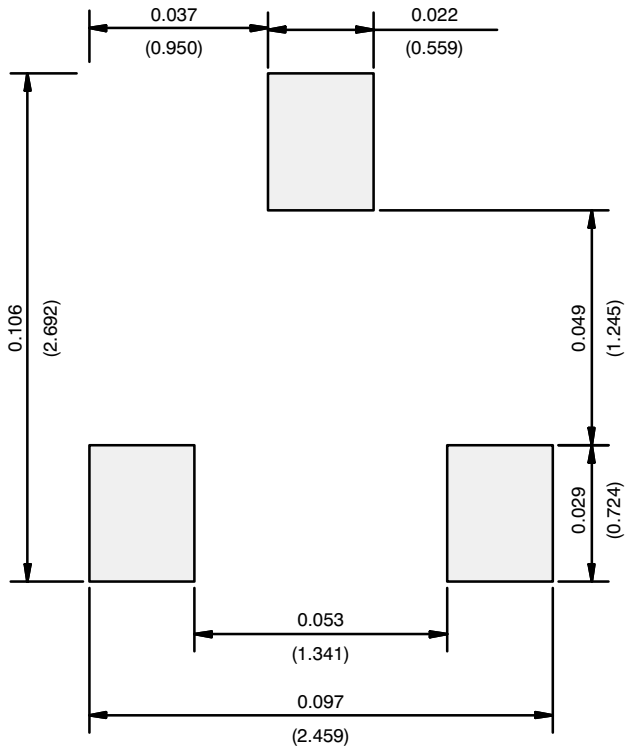

**Normalized Thermal Transient Impedance, Junction-to-Foot**

## SOT-23 (TO-236): 3-LEAD




| Dim | MILLIMETERS | | INCHES | |
|---|---|---|---|---|
| | Min | Max | Min | Max |
| **A** | 0.89 | 1.12 | 0.035 | 0.044 |
| **$A_1$** | 0.01 | 0.10 | 0.0004 | 0.004 |
| **$A_2$** | 0.88 | 1.02 | 0.0346 | 0.040 |
| **b** | 0.35 | 0.50 | 0.014 | 0.020 |
| **c** | 0.085 | 0.18 | 0.003 | 0.007 |
| **D** | 2.80 | 3.04 | 0.110 | 0.120 |
| **E** | 2.10 | 2.64 | 0.083 | 0.104 |
| **$E_1$** | 1.20 | 1.40 | 0.047 | 0.055 |
| **e** | 0.95 BSC | | 0.0374 Ref | |
| **$e_1$** | 1.90 BSC | | 0.0748 Ref | |
| **L** | 0.40 | 0.60 | 0.016 | 0.024 |
| **$L_1$** | 0.64 Ref | | 0.025 Ref | |
| **S** | 0.50 Ref | | 0.020 Ref | |
| **q** | 3° | 8° | 3° | 8° |
| ECN: S-03946-Rev. K, 09-Jul-01<br>DWG: 5479 | | | | |

## RECOMMENDED MINIMUM PADS FOR SOT-23




Recommended Minimum Pads
Dimensions in Inches/(mm)

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Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

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**Kategorilere göz atın**

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Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

**Üreticileri görün**

### Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

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